

## The RF Line VHF Power Transistors

The TP2330 device is intended for use in VHF transmitter output stages where high gain is desired.

Use of gold metallization and diffused emitter ballast resistors result in enhanced reliability and ruggedness.

- 175 MHz
- 30 W —  $P_{out}$
- 12.5 V —  $V_{CC}$
- High Gain — 10 dB @ 175 MHz

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	16	Vdc
Collector-Base Voltage	$V_{CBO}$	36	Vdc
Emitter-Base Voltage	$V_{EBO}$	4	Vdc
Collector Current — Continuous	$I_C$	8	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	80 0.46	Watts W/C
Operating Junction Temperature	$T_J$	200	°C
Storage Temperature Range	$T_{stg}$	-65 to +200	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.2	°C/W

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C = 50 \text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	16	—	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 50 \text{ mA}, I_E = 0$ )	$V_{(BR)CBO}$	36	—	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 5 \text{ mA}, I_C = 0$ )	$V_{(BR)EBO}$	4	—	—	Vdc
Collector Cutoff Current ( $V_{CE} = 15 \text{ V}, V_{BE} = 0$ )	$I_{CES}$	—	—	10	mAdc

### ON CHARACTERISTICS

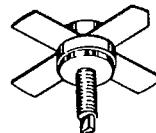
DC Current Gain ( $I_C = 1 \text{ A}, V_{CE} = 5 \text{ V}$ )	$HFE$	20	—	250	—
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### DYNAMIC CHARACTERISTICS

Output Capacitance ( $V_{CB} = 15 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ )	$C_{ob}$	—	70	100	pF
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**TP2330  
TP2330F**

**30 W — 175 MHz  
VHF POWER  
TRANSISTORS**



.380 SOE  
CASE 145D-01, STYLE 1  
TP2330

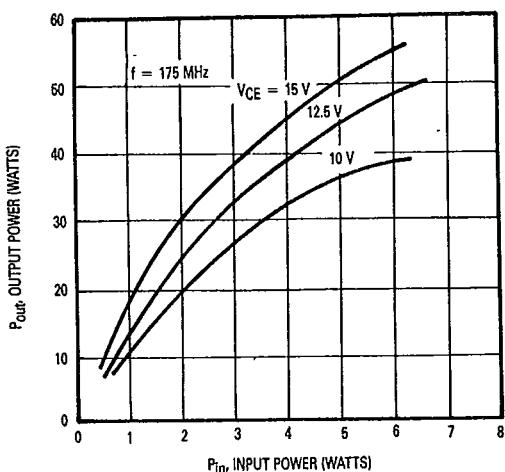
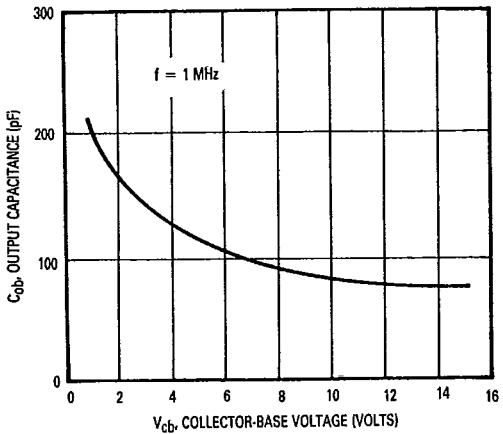
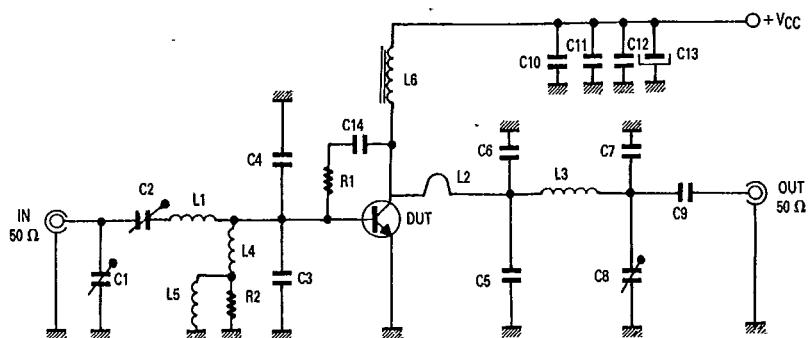


.380 SOE F  
CASE 211-07, STYLE 1  
TP2330F

(continued)

**ELECTRICAL CHARACTERISTICS — continued ( $T_C = 25^\circ\text{C}$  unless otherwise noted)**

Characteristic	Symbol.	Min	Typ	Max	Unit
<b>FUNCTIONAL TESTS</b>					
Common-Emitter Amplifier Power Gain ( $V_{CE} = 12.5 \text{ V}$ , $P_{out} = 30 \text{ W}$ , $f = 175 \text{ MHz}$ )	TP2330 TP2330F	G <sub>PE</sub> 9	10	—	dB
Collector Efficiency ( $V_{CE} = 12.5 \text{ V}$ , $P_{out} = 30 \text{ W}$ , $f = 175 \text{ MHz}$ )	$\eta_C$	60	—	—	%
Load Mismatch ( $V_{CE} = 12.5 \text{ V}$ , $P_{out} = 30 \text{ W}$ , $f = 175 \text{ MHz}$ , Load VSWR = $\infty:1$ , All Phase Angles)	$\psi$	No Degradation in Output Power			
Input Impedance, Common Emitter (Typ) ( $V_{CE} = 12.5 \text{ V}$ , $P_{out} = 30 \text{ W}$ , $f = 175 \text{ MHz}$ )		$Z_{in} = 1.05 + j0.5 \text{ Ohms}$			
Load Impedance, Common Emitter (Typ) ( $V_{CE} = 12.5 \text{ V}$ , $P_{out} = 30 \text{ W}$ , $f = 175 \text{ MHz}$ )		$Z_{Load} = 2.7 + j0.2 \text{ Ohms}$			

**TYPICAL CHARACTERISTICS**

**Figure 1. Output Power versus Frequency**

**Figure 2. Output Capacitance versus Voltage**


C1, C2 — 100 pF ARCO 423 trimmer capacitor  
 C3 — 200 pF UNELCO mica capacitor  
 C4 — 150 pF UNELCO mica capacitor  
 C5 — 120 pF UNELCO mica capacitor  
 C6 — 100 pF UNELCO mica capacitor  
 C7 — 25 pF UNELCO mica capacitor  
 C8 — 40 pF ARCO 403 trimmer capacitor  
 C9 — 1000 pF ceramic disc capacitor

C10 — 1000 pF UNELCO mica capacitor  
 C11, C14 — 100 nF ceramic capacitor  
 C12 — 10 nF ceramic capacitor  
 C13 — 47 μF 25 V electrolytic capacitor  
 L1 — 3 turns, 1 mm enameled wire, ID = 6 mm  
 L2 — Copper lead 8 x 6 mm  
 L3 — 1.5 mm wire, 30 mm length  
 L4 — 6 turns, 1 mm enameled wire, ID = 6 mm  
 L5 — 10 μH molded coil  
 L6 — 8 turns enameled wire wound on ferrite core 4C6 9 x 15 mm,  $\mu r = 120$   
 R1 — 100 Ω 1 W Carbon composition resistor  
 R2 — 10 Ω 1/2 W Carbon composition resistor

**Figure 3. 175 MHz Test Circuit**